INSTITUTE OF AERONAUTICAL ENGINEERING
(Autonomous)
Dundigal, Hyderabad - 500043
INFORMATION TECHNOLOGY
TUTORIAL QUESTION BANK

| Course Name | $:$ | Analog and Digital Electronics |
| :--- | :---: | :--- |
| Course Code | $:$ | AECB05 |
| Class | $:$ | B. Tech III Semester |
| Regulation | $:$ | IARE- R18 |
| Branch | $:$ | IT |
| Course Coordinator | $:$ | Ms. M Saritha, Assistant Professor |
| Course Faculty | $:$ | Ms. C Devi Supraja, Assistant Professor |

## COURSE OBJECTIVES:

The course should enable the students to,

| I | Introduce components such as diodes, BJTs and FETs. |
| :---: | :--- |
| II | Know the applications of components. |
| III | Understand common forms of number representation in logic circuits |
| IV | Learn basic techniques for the design of digital circuits and fundamental concepts used in the <br> design of digital systems. |
| V | Understand the concepts of combinational logic circuits and sequential circuits. |

## COURSE OUTCOMES (CO's):

| CO 1 | Acquire knowledge of electrical characteristics of ideal and practical diodes under forward and reverse bias <br> to analyze and design diode application circuits such as rectifiers. |
| :---: | :--- |
| CO 2 | Utilize operational principles of bipolar to derive appropriate small-signal models and use them for the <br> analysis of basic circuits. |
| CO 3 | Understand the basic concept of number systems, Boolean algebra principles and minimization techniques <br> for Boolean algebra |
| CO 4 | Analyze Combination logic circuit such as multiplexers, adders, decoders |
| CO 5 | Understand about synchronous and asynchronous sequential logic circuits. |

## COURSE LEARNING OUTCOMES (CLO's):

| AECB05.01 | Understand and analyze diodes operation and their characteristics in order to design basic form circuits |
| :--- | :--- |
| AECB05.02 | Explain half wave rectifier for the given specifications. |
| AECB05.03 | Design full wave rectifier for the given specifications |
| AECB05.04 | Design rectifier with capacitive filter for the given specifications |
| AECB05.05 | Understand the different parameters of transistors such as depletion width and channel width for <br> understanding the functioning and design of this component. |
| AECB05.06 | Estimate the performance of BJT on the basis of their operation and working. |
| AECB05.07 | Explain the operation of Operating Point and Load Line Analysis |
| AECB05.08 | Explain the operation of CB,CE,CC I/O Characteristics |
| AECB05.09 | Understand the importance of h-parameter model |


| AECB05.10 | Understand the basic concept of number systems, Binary addition and subtraction for digital systems. |
| :--- | :--- |
| AECB05.11 | Explain the complements of Binary \& Decimal number systems |
| AECB05.12 | Discuss about digital logic gates, error detecting and Correcting codes for digital systems. |
| AECB05.13 | Illustrate the switching algebra theorems and apply them for reduction of Boolean function. |
| AECB05.14 | Identify the importance of SOP and POS canonical forms in the minimization or other optimization of <br> Boolean formulas in general and digital circuits. |
| AECB05.15 | Evaluate functions using various types of minimizing algorithms like Karnaugh map or tabulation method. |
| AECB05.16 | Design Gate level minimization using KMaps and realize the Boolean function using logic gates. |
| AECB05.17 | Analyze the design procedures of Combinational logic circuits like adders,Subtractors. |
| AECB05.18 | Analyze the design of decoder, demultiplexer, and comparator using combinational logic circuit. |
| AECB05.19 | Understand bi-stable elements like latches flip-flop and Illustrate the excitation tables of different flip flops |
| AECB05.20 | Understand the concept of Shift Registers and implement the bidirectional and universal shift registers. |
| AECB05.21 | Implement the synchronous\& asynchronous counters using design procedure of sequential circuit and <br> excitation tables of flip - flops. |

## TUTORIAL QUESTION BANK

| MODULE-IDIODE AND APPLICATIONS |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| Part - A (Short Answer Questions) |  |  |  |  |
| S. No | Question | Blooms Taxonomy Level | Course Outcomes | Course <br> Learning <br> Outcomes |
| 1 | Explain about forward bias and reverse bias of diode? | Understand | CO 1 | AECB05.01 |
| 2 | Write the Applications of diode? | Understand | CO 1 | AECB05.01 |
| 3 | Draw the V-I characteristics of diode? | Understand | CO 1 | AECB05.01 |
| 4 | List the differences between ideal diode and practical diode? | Remember | CO 1 | AECB05.01 |
| 5 | Define diffusion and transition capacitance? | Remember | CO 1 | AECB05.01 |
| 6 | Define static and dynamic resistance? | Remember | CO 1 | AECB05.01 |
| 7 | Explain the load line Analysis of diode? | Understand | CO 1 | AECB05.01 |
| 8 | Define Fermi level? | Remember | CO 1 | AECB05.01 |
| 9 | Write the equation of diode current. | Remember | CO 1 | AECB05.01 |
| 10 | Define cut-in voltage? | Remember | CO 1 | AECB05.01 |
| 11 | Write the differences between avalanche and zener breakdown mechanisms? | Understand | CO 1 | AECB05.01 |
| 12 | Define depletion region? | Remember | CO 1 | AECB05.01 |
| 13 | Explain the temperature dependence of V-I characteristics of PN diode? | Understand | CO 1 | AECB05.01 |
| 14 | Define rectifier? | Remember | CO 1 | AECB05.02 |
| 15 | Give the advantages and disadvantages of HWR and FWR? | Understand | CO 1 | AECB05.02 |
| 16 | Define ripple factor and mention the ripple factor of HWR and FWR | Remember | CO 1 | AECB05.03 |
| 17 | Define transformer utilization factor and mention the TUF of HWR and FWR | Remember | CO 1 | AECB05.03 |
| 18 | Define efficiency and mention the efficiency of HWR and FWR. | Remember | CO 1 | AECB05.03 |
| 19 | Define drift and diffusion currents? | Remember | CO 1 | AECB05.01 |
| 20 | What is the need for a filter in rectifier? | Remember | CO 1 | AECB05.04 |
| Part - B (Long Answer Questions) |  |  |  |  |
| 1 | Explain the formation of depletion region in an open-circuited p-n junction diode and also the effect of forward and reverse biasing of $\mathrm{p}-\mathrm{n}$ junction on the depletion region with neat sketches? | Remember | CO 1 | AECB05.01 |
| 2 | Analyze the differences between drift and diffusion current in a semiconductor with neat diagrams? | Understand | CO 1 | AECB05.01 |
| 3 | Explain the operation of PN- junction diode under forward bias and reverse bias condition and Sketch the V-I characteristics of $\mathrm{p}-\mathrm{n}$ junction diode. | Understand | CO 1 | AECB05.01 |
| 4 | Explain the temperature dependence of VI characteristics of PN diode? | Understand | CO 1 | AECB05.01 |
| 5 | Derive the diode current equation and discuss various parameters involved in the equation | Remember | CO 1 | AECB05.01 |
| 6 | Explain the Zener and avalanche breakdown mechanisms of p-n junction diode in detail? | Understand | CO 1 | AECB05.01 |
| 7 | Explain the switching functions of DIODE with a suitable wave forms. | Understand | CO 1 | AECB05.01 |
| 8 | Explain the differences between Static and dynamic resistances of a p-n diode. | Remember | CO 1 | AECB05.01 |
| 9 | Draw the circuit diagram of a half wave rectifier. Explain the operation of the circuit with relevant waveforms. | Remember | CO 1 | AECB05.02 |
| 10 | Define and derive the expressions for the following of a half wave rectifier with resistive load. <br> i) Ripple factor ii) Peak inverse voltage iii) Efficiency iv) Average current v) RMS current vi) Transformer utilization factor | Remember | CO 1 | AECB05.02 |


| 11 | Draw the circuit diagrams of a full wave rectifier and Bridge rectifier. Explain the operation of the circuit with relevant waveforms. | Remember | CO 1 | AECB05.03 |
| :---: | :---: | :---: | :---: | :---: |
| 12 | Define and derive the expressions for the following of a full wave rectifier with resistive load. <br> i) Ripple factor ii) Peak inverse voltage iii) Efficiency iv) Average current v) RMS current vi) Transformer utilization factor | Remember | CO 1 | AECB05.03 |
| 13 | Distinguish between Half wave rectifier, center tapped full wave rectifier and bridge rectifier | understand | CO 1 | AECB05.03 |
| 14 | Explain the operation of capacitor filter and derive expression for ripple factor?(HWR) | Understand | CO 1 | AECB05.04 |
| 15 | Explain the operation of C -section filter and derive expression for ripple factor?(FWR) | Understand | CO 1 | AECB05.04 |
| 16 | Discuss the merits and Demerits of half wave, full wave and bridge rectifier. | Remember | CO 1 | AECB05.03 |
| 17 | Explain the switching characteristics of diode with the help of simple diode circuit. | Remember | CO 1 | AECB05.01 |
| 18 | What is the ripple factor if a power supply of $220 \mathrm{~V}, 50 \mathrm{~Hz}$ is to be Full Wave rectified and filtered with a $220 \mu \mathrm{~F}$ capacitor before delivering to a resistive load of $120 \Omega$ ? Compute the value of the capacitor for the ripple factor to be less than $15 \%$. | Remember | CO 1 | AECB05.04 |
| 19 | A bridge rectifier uses four identical diodes having forward resistance of $5 \Omega$ each. Transformer secondary resistance is $5 \Omega$ and the secondary voltage of $30 \mathrm{~V}(\mathrm{rms})$.Determine the dc output voltage for $\mathrm{IDC}=200 \mathrm{~mA}$ and the value of the ripple voltage. | Understand | CO 1 | AECB05.03 |
| 20 | A HWR circuit supplies 100 mA DC current to a $250 \Omega$ load. Find the DC output voltage, PIV rating of a diode and the r.m.s. voltage for the transformer supplying the rectifier? | Remember | CO 1 | AECB05.02 |
| Part - C(Problem Solving And Critical Thinking Questions) |  |  |  |  |
| 1 | Find the value of D.C. resistance and A.C resistance of a Germanium junction diode at $250^{\circ} \mathrm{C}$ with reverse saturation current, Io $=25 \mu \mathrm{~A}$ and at an applied voltage of 0.2 V across the diode? | Remember | CO 1 | AECB05.01 |
| 2 | The reverse saturation current of a silicon $\mathrm{p}-\mathrm{n}$ function diode at an operating temperature of 270 C is 50 nA . Estimate the dynamic forward and reverse resistances of the diode for applied voltages of 0.8 V and -0.4 V respectively? | Remember | CO 1 | AECB05.01 |
| 3 | Determine the values of forward current in the case of P-N junction diode, with $\mathrm{I}_{0}=10 \mu \mathrm{~A} \mathrm{Vf}=0.8 \mathrm{~V}$ at $\mathrm{T}=300^{\circ} \mathrm{K}$. Assume silicon diode? | understand | CO 1 | AECB05.01 |
| 4 | An Ideal Ge P-n junction diode has a reverse saturation current of $30 \mu \mathrm{~A}$ at a temperature of $125^{\circ} \mathrm{C}$. Find the dynamic resistance for a 0.2 V bias in the forward and reverse direction | Understand | CO 1 | AECB05.01 |
| 5 | The voltage across a silicon diode at room temperature of 300 K is 0.7 V when 2 ma current flows through it. If the voltage increases to 0.75 v , Evaluate the diode current assuming $\mathrm{VT}=26 \mathrm{mv}$. | Understand | CO 1 | AECB05.01 |


| 6 | Determine the values of forward current in the case of $\mathrm{P}-\mathrm{N}$ junction diode, with $\mathrm{I} 0=10 \mu \mathrm{~A} \mathrm{Vf}=0.8 \mathrm{~V}$ at $\mathrm{T}=3000 \mathrm{~K}$. Assume silicon diode? | Remember | CO 1 | AECB05.01 |
| :---: | :---: | :---: | :---: | :---: |
| 7 | A p-n junction diode has a reverse saturation current of $30 \mu \mathrm{~A}$ at a temperature of $125^{\circ} \mathrm{C}$. At the same temperature, find the dynamic resistance for 0.2 V bias in forward and reverse direction? | Remember | CO 1 | AECB05.01 |
| 8 | The voltage across a silicon diode at room temperature of $300^{0} \mathrm{~K}$ is 0.7 V when 2 ma current flows through it. If the voltage increases to 0.75 v , Evaluate the diode current assuming $\mathrm{VT}=26 \mathrm{mv}$. | Remember | CO 1 | AECB05.01 |
| 9 | Determine the dynamic forward and reverse resistance of p-n junction silicon diode when the applied voltage is 0.25 V at $\mathrm{T}=3000 \mathrm{~K}$ with give $\mathrm{I} 0=2 \mu \mathrm{~A}$ ? | Remember | CO 1 | AECB05.01 |
| 10 | A full wave bridge rectifier having load resistance of $100 \Omega$ is fed with 220 V , Assuming the diodes are ideal, Find the following terms, <br> i) DC output voltage <br> ii) Peak inverse voltage <br> iii) Rectifier efficiency. | understand | CO 1 | AECB05.03 |
| MODULE-IIBIPOLAR JUNCTION TRANSISTOR (BJT) |  |  |  |  |
| Part - A (Short Answer Questions) |  |  |  |  |
| 1 | Define Transistor? | Remember | CO 2 | AECB05.05 |
| 2 | Define operating point Q? | Understand | CO 2 | AECB05.06 |
| 3 | Draw the symbols of NPN and PNP transistor and mark the current directions? | Understand | CO 2 | AECB05.05 |
| 4 | Draw the hybrid model of a CB configuration? | Remember | CO 2 | AECB05.06 |
| 5 | Explain the breakdown in transistor? | Understand | CO 2 | AECB05.06 |
| 6 | Explain the transistor switching times? | Understand | CO 2 | AECB05.06 |
| 7 | Explain the phenomena of reach through in a transistor. | Understand | CO 2 | AECB05.07 |
| 8 | Define early effect or base width modulation? | Remember | CO 2 | AECB05.05 |
| 9 | List the advantages of h-parameters | Understand | CO 2 | AECB05.06 |
| 10 | Explain about the various regions in a transistor? | Understand | CO 2 | AECB05.06 |
| 11 | When does a transistor act as a switch? | Understand | CO 2 | AECB05.07 |
| 12 | Draw the output characteristics of NPN transistor in CE Configuration? | Understand | CO 2 | AECB05.06 |
| 13 | Explain the criteria for fixing operating point | Understand | CO 2 | AECB05.06 |
| 14 | Describe the various current components in a BJT? | Remember | CO 2 | AECB05.06 |
| 15 | Write the relation between IC, $\beta$, IB and ICBO in a BJT? | Remember | CO 2 | AECB05.06 |
| 16 | Draw the circuit diagram of Common base, common emitter and common collector configurations | Understand | CO 2 | AECB05.08 |
| 17 | Draw the input characteristics of common emitter configuration. | Understand | CO 2 | AECB05.08 |
| 18 | Draw the small signal model of a CE configuration? | Understand | CO 2 | AECB05.09 |
| 19 | Define hie and hfe in CE configuration? | Remember | CO 2 | AECB05.09 |
| 20 | Define hoe and hre in CB configuration? | Understand | CO 2 | AECB05.09 |
| Part- B (Long Answer Questions) |  |  |  |  |
| 1 | With a neat diagram explain the various current components in an NPN bipolar junction transistor and hence derive the general equation for collector current, IC. | Understand | CO 2 | AECB05.05 |
| 2 | Define Early-effect; Explain why it is called as base-width modulation? Discuss its consequences in transistors in detail? | Remember | CO 2 | AECB05.06 |
| 3 | What is thermal runaway in transistors? Obtain the condition for thermal stability in transistors? | Understand | CO 2 | AECB05.06 |
| 4 | Explain clearly the DC and AC load line and also explain how to obtain quiescent point graphically for a transistor amplifier of CE configuration. | Remember | CO 2 | AECB05.07 |
| 5 | Draw the input and output characteristics of a transistor in common emitter Configurations and explain its working? | Understand | CO 2 | AECB05.08 |


| 6 | Draw the input and output characteristics of a transistor in common base configurations? | Remember | CO 2 | AECB05.08 |
| :---: | :---: | :---: | :---: | :---: |
| 7 | Draw the input and output characteristic of a transistor in common collector configurations? | Understand | CO 2 | AECB05.08 |
| 8 | Describe the significance of the terms, $\alpha, \beta$ and $\gamma$ and derive the relation between them? | Understand | CO 2 | AECB05.06 |
| 9 | Explain the constructional details and operation of Bipolar Junction Transistor with neat sketches? | Remember | CO 2 | AECB05.05 |
| 12 | Draw the small-signal model of common base BJT amplifier. Derive expressions for voltage gain, input resistance current gain and output resistance? | Understand | CO 2 | AECB05.09 |
| 13 | Draw the small-signal model of common collector BJT amplifier. Derive expressions for voltage gain, input resistance, current gain and output resistance? | Remember | CO 2 | AECB05.09 |
| 14 | Draw the small-signal model of common emitter BJT amplifier. Derive expressions for voltage gain, input resistance current gain and output resistance? | Understand | CO 2 | AECB05.09 |
| 15 | Derive the equations of current gain Ai, voltage gain Av, input impedance Zi , output admittance Yo, voltage gain with Rs(Avs), current gain with Rs(Ais) using a general two port active network. | Understand | CO 2 | AECB05.09 |
| 16 | Write the expression for collector current (IC) in terms of emitter current (IE) and $\alpha \mathrm{dc}$ and in terms of base current (IB) and $\alpha \mathrm{dc}$ | Understand | CO 2 | AECB05.09 |
| 17 | Draw the hybrid model of a CC configuration? | Remember | CO 2 | AECB05.09 |
| 18 | Define $\alpha, \beta, \gamma$ of a transistor and show how they are related to each other | Understand | CO 2 | AECB05.09 |
| 19 | Define following <br> i) Active Region <br> ii) Cut off region <br> iii) Saturation region | Understand | CO 2 | AECB05.07 |
| 20 | What is the importance of DC load line | Remember | CO 2 | AECB05.07 |
| Part - C(Problem Solving And Critical Thinking Questions) |  |  |  |  |
| 1 | A common collector circuit has the following components $\mathrm{R} 1=27 \mathrm{k} \Omega, \mathrm{R} 2=27 \mathrm{k} \Omega, \mathrm{Re}=5.6 \mathrm{k} \Omega, \mathrm{RL}=47 \mathrm{k} \Omega, \mathrm{Rs}=600 \Omega$. The transistor parameters are hie $=1 \mathrm{k} \Omega$, hfe $=85$ and hoe $=2 \mu \mathrm{~A} / \mathrm{V}$. Determine Ai, Ri, Av, Ro. | Understand | CO 2 | AECB05.09 |
| 2 | A common collector circuit has the following components $\mathrm{R} 1=27 \mathrm{k} \Omega, \mathrm{R} 2=27 \mathrm{k} \Omega, \mathrm{Re}=5.6 \mathrm{k} \Omega, \mathrm{RL}=47 \mathrm{k} \Omega, \mathrm{Rs}=600 \Omega$. The transistor parameters are hie $=1 \mathrm{k} \Omega$, hfe $=85$ and hoe $=2 \mu \mathrm{~A} / \mathrm{V}$. Determine Ai, Ri, Av, Ro. | Remember | CO 2 | AECB05.09 |
| 3 | A Common emitter circuit has the following components. $\mathrm{Rs}=1 \mathrm{k}, \mathrm{R} 1=110 \mathrm{~K}, \quad \mathrm{R} 2=12 \mathrm{~K} \quad \mathrm{Rc}=6 \mathrm{~K}$. h-parameters are hie $=1.2 \mathrm{~K}$, hre $=2.5 * 10-4$, hfe $=75$,hoe $=25 u$ A/V. Draw theequivalent hybrid model and calculate Ai, Ri, Ro and Av? | Understand | CO 2 | AECB05.09 |
| 4 | The h-parameters of a transistor used in a CE circuit are hie $=1.0 \mathrm{~K}$, hre $=10 \times 10-4$, hfe $=50$, hoe $=100 \mathrm{~K}$. The load resistance for the transistor is 1 K in the collector circuit. Determine Ri, Ro, AV\& Ai in the amplifier stage. (Assume Rs = 1000)? | Understand | CO 2 | AECB05.09 |
| 5 | Compute current gain, voltage gain, input and output impedance of the CB amplifier if it is driven by a voltage source of internal resistance $\mathrm{Rs}=1 \mathrm{k}$. The load impedance is $\mathrm{RL}=1 \mathrm{~K}$. The transistor parameters are $\mathrm{hib}=22$, $\mathrm{hfb}=-0.98$, $\mathrm{hrb}=2.9 \times 10-4$, hob $=0.5 \mu \mathrm{~A} / \mathrm{V}$. | Remember | CO 2 | AECB05.09 |
| 6 | A bipolar junction transistor with hie $=1100 \Omega$, hfe $=50$, hre $=2.4 \times 10-4$, hoe $=25 \mu \mathrm{~A} / \mathrm{V}$, is to drive a load of $1 \mathrm{~K} \Omega$ in Emitter-Follower arrangement. Estimate AV, AI, Ri\& R0? | Understand | CO 2 | AECB05.09 |
| 7 | Draw small signal equivalent circuit of Emitter Follower using accurate hparameter model. For the emitter follower | Understand | CO 2 | AECB05.09 |


|  | circuit with $\mathrm{RS}=0.5 \mathrm{~K}$ and $\mathrm{RL}=5 \mathrm{~K}$, calculate $\mathrm{Ri}, \mathrm{AV}$ and RO . Assume, hfe $=50$, hie $=1 \mathrm{~K}$, hoe $=25 \mu \mathrm{~A} / \mathrm{V}$. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| 8 | A silicon NPN transistor has Ico $=20 \mathrm{nA}$ and $\beta=150$, Vbe $=$ 0.7 V . It is operated in Common Emitter Configuration having $\mathrm{Vbb}=4.5 \mathrm{~V}, \mathrm{Rb}=150 \mathrm{~K}, \mathrm{Rc}=3 \mathrm{~K}, \mathrm{Vcc}=12 \mathrm{~V}$. Find the emitter, base and collector currents and also verify in which region the transistor operates. What will happen if the value of the collector resistance is increased to very high values? | Understand | CO 2 | AECB05.06 |
| 9 | Draw small signal equivalent circuit of Emitter Follower using accurate hparameter model. For the emitter follower circuit with $\mathrm{RS}=2 \mathrm{~K}$ and $\mathrm{RL}=5 \mathrm{~K}$, calculate $\mathrm{Ri}, \mathrm{AV}$ and RO . Assume, $\mathrm{hfe}=50$, hie $=1 \mathrm{~K}$, hoe $=25 \mu \mathrm{~A} / \mathrm{V}$. | Understand | CO 2 | AECB05.09 |
| 10 | A common emitter circuit has the following components $\mathrm{R} 1=27 \mathrm{k} \Omega, \mathrm{R} 2=27 \mathrm{k} \Omega, \mathrm{Re}=5.6 \mathrm{k} \Omega, \mathrm{RL}=47 \mathrm{k} \Omega, \mathrm{Rs}=600 \Omega$. The transistor parameters are hie $=1 \mathrm{k} \Omega$, hfe $=85$ and hoe $=2 \mu \mathrm{~A} / \mathrm{V}$. Determine Ai, Ri, Av, Ro. | Understand | CO 2 | AECB05.09 |
| $\begin{gathered} \text { MODULE-III } \\ \text { NUMBER SYSTEMS } \\ \hline \end{gathered}$ |  |  |  |  |
| Part - A (Short Answer Questions) |  |  |  |  |
| 1 | Write short notes on binary number systems. | Remember | CO 3 | AECB05.10 |
| 2 | Discuss 1"s and 2"s complement. | Understand | CO 3 | AECB05.11 |
| 3 | Discuss octal number system. | Understand | CO 3 | AECB05.10 |
| 4 | Convert the octal numbers into binary, decimal and Hexadecimal numbers $(45.5) 8,(32.2) 8 .$ | Understand | CO 3 | AECB05.10 |
| 5 | Show an example to convert gray code to binary code. | Remember | CO 3 | AECB05.11 |
| 6 | Describe a short note on four bit BCD codes. | Remember | CO 3 | AECB05.11 |
| 7 | Illustrate about unit -distance code? State where they are used. | Understand | CO 3 | AECB05.11 |
| 8 | List the applications of error correcting codes. | Remember | CO 3 | AECB05.12 |
| 9 | Convert 10101101.0111 to octal equivalent and hexadecimal equivalent. | Understand | CO 3 | AECB05.10 |
| 10 | Give the examples of unit distance codes | Understand | CO 3 | AECB05.11 |
| 11 | Convert (4075) $)_{8}$ into base 5. | Understand | CO 3 | AECB05.10 |
| CIE II |  |  |  |  |
| 1 | Which gates are called as universal gate justify. | Understand | CO 3 | AECB05.12 |
| 2 | State DeMorgan's theorem | Remember | CO 3 | AECB05.13 |
| 3 | State Duality theorem. | Remember | CO 3 | AECB05.13 |
| 4 | Draw the symbols and truth tables of XOR and XNOR gates | Remember | CO 3 | AECB05.12 |
| 5 | Define sum of products and product of sum | Remember | CO 3 | AECB05.14 |
| 6 | State and prove the distributive property of Boolean algebra. | Remember | CO 3 | AECB05.13 |
| 7 | Simplify ABC+AB'C+ABC' | Understand | CO 3 | AECB05.12 |
| 8 | Convert the given expression in standard SOP form $\mathrm{Y}=\mathrm{AC}+\mathrm{AB}+\mathrm{BC}$ | Remember | CO 3 | AECB05.14 |
| 9 | Convert the given expression in standard POS form $\mathrm{Y}=(\mathrm{A}+\mathrm{B})(\mathrm{B}+\mathrm{C})(\mathrm{A}+\mathrm{C})$. | Remember | CO 3 | AECB05.14 |
| Part - B (Long Answer Questions) |  |  |  |  |
| 1 | Explain error occurred in data transmission can be detected using parity bit? | Understand | CO 3 | AECB05.12 |
| 2 | Define weighted codes and non weighted codes with examples? | Remember | CO 3 | AECB05.11 |
| 3 | Explain what do you mean by error detection and correcting code with examples. | Understand | CO 3 | AECB05.12 |
| 4 | Explain the gray to binary and binary- to- gray conversion with examples | Understand | CO 3 | AECB05.11 |
| 5 | Explain the conversion of AND/OR/NOT logic to NAND/ NOR logic with example. | Understand | CO 3 | AECB05.14 |
| 6 | Explain Self complemented codes. | Understand | CO 3 | AECB05.11 |
| 7 | Differentiate between BCD code and 2421 code and XS-3. | Understand | CO 3 | AECB05.11 |


| 8 | Given the 8bit data word 01011011, generate the 12 bit composite word for the hamming code that corrects and detects single errors. | Understand | CO 3 | AECB05.12 |
| :---: | :---: | :---: | :---: | :---: |
| 9 | Write the first 10 decimal digits in base 3 and base 16. | Remember | CO 3 | AECB05.10 |
| 10 | A device transmits the binary data using even parity, the message is 1011001 . Identify the receiver receives the correct data or not. | Remember | CO 3 | AECB05.12 |
| 11 | Convert the given expression in standard POS form $\mathrm{Y}=(\mathrm{A}+\mathrm{B})(\mathrm{B}+\mathrm{C})(\mathrm{A}+\mathrm{C})$. | Remember | CO 3 | AECB05.14 |
| 12 | Obtain the canonical SOP form of the following functions. <br> i) $\mathrm{Y}(\mathrm{A}, \mathrm{B})=\mathrm{A}+\mathrm{B}$. ii) $\mathrm{Y}(\mathrm{A}, \mathrm{B}, \mathrm{C}, \mathrm{D})=\mathrm{AB}+\mathrm{ACD}$ | Understand | CO 3 | AECB05.10 |
| 13 | Simplify the expression $\mathrm{Z}=\mathrm{AB}+\mathrm{AB}^{\prime}$. ( $\left.\mathrm{A}^{\prime} \mathrm{C}^{\prime}\right)^{\prime}$ | Remember | CO 3 | AECB05.10 |
| 14 | Simplify the following 3 variable expression using Boolean algebra $\mathrm{Y}=\Pi \mathrm{M}(3,5,7)$. | Remember | CO 3 | AECB05.10 |
| 15 | Simplify the following 3 variable expression using Boolean algebra $\mathrm{Y}=\sum \mathrm{m}(1,3,5,7)$. | Understand | CO 3 | AECB05.10 |
| CIE -II |  |  |  |  |
| 1 | Give the Boolean expressions, symbols and truth tables for following gates, <br> i) AND ii) NOR iii) EX-OR iv) OR v) EX-NOR. | Understand | CO 3 | AECB05.12 |
| 2 | Realize all the logic gates using NAND gate. | Remember | CO 3 | AECB05.14 |
| 3 | Realize all the logic gates using NOR gate. | Remember | CO 3 | AECB05.12 |
| 4 | Explain standard SOP and POS forms with examples | Remember | CO 3 | AECB05.14 |
| 5 | State and prove Boolean theorems and properties. | Understand | CO 3 | AECB05.13 |
| Part - C (Problem Solving And Critical Thinking Questions) |  |  |  |  |
| 1 | Convert the following Hexadecimal number to their Decimal equivalent (EAF1)16. | Remember | CO 3 | AECB05.10 |
| 2 | What is the gray code equivalent of the Hex Number 3A7. Find 9's complement of (25.639)10. | Remember | CO 3 | AECB05.10 |
| 3 | Find 7 bit hamming code for given message 1010 by using odd parity. | Understand | CO 3 | AECB05.12 |
| 4 | Perform the subtraction using 1's Complement i) $\quad(11010)_{2}-(10000)_{2}$ ii) $\quad(1000100)_{2}-(1010100)_{2}$ ii | Remember | CO 3 | AECB05.11 |
| 5 | Convert following hexadecimal number to decimal, <br> i) F2816 ii) BC216 | Understand | CO 3 | AECB05.11 |
| CIE-II |  |  |  |  |
| 1 | Implement $\mathrm{Y}=\mathrm{Y}=\mathrm{AB}^{\prime}+\mathrm{A}^{\prime} \mathrm{B}$ using 2 input NAND gates | Remember | CO 3 | AECB05.14 |
| 2 | Simplify using postulates and theorems of Boolean algebra i) $\quad\left(\mathrm{X}+\mathrm{Y}^{\prime}+\mathrm{XY}\right)\left(\mathrm{X}+\mathrm{Y}^{\prime}\right) \mathrm{X}^{\prime} \mathrm{Y}$ <br> ii) $\quad(\mathrm{AB}+\mathrm{C}+\mathrm{D})\left(\mathrm{C}^{\prime}+\mathrm{D}\right)\left(\mathrm{C}^{\prime}+\mathrm{D}+\mathrm{E}\right)$ | Remember | CO 3 | AECB05.13 |
| 3 | For each of the following expressions, construct the corresponding logic circuit using AND/OR/INVERT logic. <br> i) $\mathrm{Y}=\mathrm{AB}(\mathrm{C}+\mathrm{D})$ <br> ii) $\mathrm{Z}=(\mathrm{W}+\mathrm{PQ})^{\prime}$ | Remember | CO 3 | AECB05.13 |
| 4 | Implement $\mathrm{Y}=\mathrm{AB}^{\prime}+\mathrm{A}^{\prime} \mathrm{B}$ using 2 input NOR gates | Understand | CO 3 | AECB05.14 |
| 5 | Realize X-OR operation a)NAND gate b)NOR gate | Remember | CO 3 | AECB05.12 |
| MODULE-IVMINIMIZATION OF BOOLEAN FUNCTIONS |  |  |  |  |
| Part - A (Short Answer Questions) |  |  |  |  |
| 1 | Realize $16 \times 1$ Mux using only $2 \times 1$ Mux | Understand | CO 4 | AECB05.18 |
| 2 | Design logic circuit for parity bit generator | Remember | CO 4 | AECB05.18 |
| 3 | What is decoder? How do you convert a decoder in to a DeMultiplexer | Understand | CO 4 | AECB05.18 |
| 4 | Design BCD to gray code converter and realize using logic gates. | Understand | CO 4 | AECB05.18 |
| 5 | What is K-Map and State the limitations of karnaugh map. | Remember | CO 4 | AECB05.15 |
| 6 | What do you mean by adder circuit? | Understand | CO 4 | AECB05.17 |


| 7 | State the truth table for 1 bit half adder. | Remember | CO 4 | AECB05.17 |
| :---: | :---: | :---: | :---: | :---: |
| 8 | Design a logic circuit to convert BCD and gray code. | Understand | CO 4 | AECB05.18 |
| 9 | Design Full adder using Logic Gates. | Remember | CO 4 | AECB05.17 |
| 10 | Design Half subtractor using NAND Gates. | Understand | CO 4 | AECB05.17 |
| 11 | Design a Full adder using NOR Gates. | Remember | CO 4 | AECB05.17 |
| 12 | Design Half subtractor using NOR Gates | Understand | CO 4 | AECB05.17 |
| 13 | Design a Full subtractor using NAND Gates. | Remember | CO 4 | AECB05.17 |
| 14 | Design a Full subtractor using NOR Gates. | Understand | CO 4 | AECB05.17 |
| 15 | State the truth table for 1 bit full adder. | Remember | CO 4 | AECB05.17 |
| 16 | Design a Full adder using NAND Gates. | Remember | CO 4 | AECB05.17 |
| 17 | How do you compare serial adder and parallel adder | Remember | CO 4 | AECB05.17 |
| 18 | Explain the terms multiplexer and de multiplexer | Remember | CO 4 | AECB05.17 |
| 19 | List some of the applications of multiplexer and de multiplexer | Remember | CO 4 | AECB05.17 |
| 20 | Explain about ripple carry adder | Remember | CO 4 | AECB05.17 |
| Part - B (Long Answer Questions) |  |  |  |  |
| 1 | Design 4 bit parallel adder using full adders. Remember | Understand | CO 4 | AECB05.17 |
| 2 | Design a excess-3 adder using 4-bit parallel binary adder and logic gates. B) What are the applications of full adders? | Remember | CO 4 | AECB05.17 |
| 3 | Explain the operation of 4 to 16 decoder. | Understand | CO 4 | AECB05.18 |
| 4 | Explain the differences between multiplexers and Demultiplexers with the help of neat logic diagrams. | Remember | CO 4 | AECB05.18 |
| 5 | Design a 64:1 MUX using 8:1 MUXs. | Understand | CO 4 | AECB05.18 |
| 6 | Design a 4 bit parallel adder using Full adder modules. | Remember | CO 4 | AECB05.17 |
| 7 | Implement the given function in 4:1 mux $\mathrm{f}=\Sigma \mathrm{m}(0,1,3,5,6)$ | Understand | CO 4 | AECB05.18 |
| 8 | Design a full adder using two half adders and OR gate. | Remember | CO 4 | AECB05.17 |
| 9 | Design a 4-bit Binary Adder using full adder. | Understand | CO 4 | AECB05.17 |
| 10 | Design a combinational circuit that complement of BCD digit $\quad$ generates the 9"s | Remember | CO 4 | AECB05.18 |
| 11 | Design a combinational circuit that generates logic „ ${ }^{\text {ce }}$ for odd inputs. | Understand | CO 4 | AECB05.18 |
| 12 | Explain the working of carry look-ahead generator. | Remember | CO 4 | AECB05.17 |
| 13 | Explain the design procedure for code converter with the help of example | Understand | CO 4 | AECB05.18 |
| 14 | Design a logic circuit to convert gray code to binary code. | Remember | CO 4 | AECB05.18 |
| 15 | Design a logic circuit to convert binary code to gray code. | Understand | CO 4 | AECB05.18 |
| 16 | Design a logic circuit to convert BCD code to binary code. | Remember | CO 4 | AECB05.18 |
| 17 | Realize the Boolean expression for half subtractor. |  | CO 4 | AECB05.17 |
| 18 | Design a combinatorial circuit that accepts a three bit number and generates an output Binary number equal to the cube of the given input number. | Remember | CO 4 | AECB05.18 |
| 19 | Implement the circuit to produce the octal number for given 4 bit binary number. | Understand | CO 4 | AECB05.18 |
| 20 | Design an 8424 to 2421 BCD code converter and draw its logic diagram. | Understand | CO 4 | AECB05.18 |
| Part - C (Problem Solving And Critical Thinking Questions) |  |  |  |  |
| 1 | $\mathrm{F}(\mathrm{w}, \mathrm{x}, \mathrm{y}, \mathrm{z})=\sum \mathrm{m}(1,4,5,6,7,9,14,15) \quad$ Realize using De- Multiplexer | Remember | CO 4 | AECB05.18 |
| 2 | Design a 4-bit Combinational circuit which generates the output as $2^{\text {ces }}$ complement of input binary number. | Understand | CO 4 | AECB05.18 |
| 3 | Simplify the following Boolean expressions using K-map and implement it by using NOR gates. A) $\mathrm{F}(\mathrm{A}, \mathrm{B}, \mathrm{C}, \mathrm{D})=\mathrm{AB}^{\prime} \mathrm{C}^{\prime}$ $\left.+A C+A^{\prime} C D^{\prime} b\right) F(W, X, Y, Z)=w^{\prime} x^{\prime} y^{\prime} z^{\prime}+w^{\prime} y^{\prime} z^{\prime}+w^{\prime} x x^{\prime} y z+$ wxyz | Understand | CO 4 | AECB05.16 |
| 4 | Simplify the following using Tabular method. $\mathrm{F}(\mathrm{A}, \mathrm{B}, \mathrm{C}, \mathrm{D})=\sum(1,5,6,12,13,14)+\mathrm{d} \sum(2,4)$ $\sum \mathrm{m}(1,2,3,5,9,12,14,15)+\mathrm{d}(4,8,11)$ | Remember | CO 4 | AECB05.16 |
| 5 | Design a combinatorial circuit that converts a decimal digit from $2,4,2,1$ code to the $8,4,2,1$ code? | Understand | CO 4 | AECB05.18 |
| 6 | Design a combinatorial circuit that accepts a three bit number | Remember | CO 4 | AECB05.18 |


|  | and generates an output Binary number equal to the square of the input number. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| 7 | 4 Design a 4-bit Combinational circuit which generates the output as 1 "s complement of input binary number. | Understand | CO 4 | AECB05.18 |
| 8 | Construct and explain the working of decimal adder. | Remember | CO 4 | AECB05.17 |
| 9 | Realize the Boolean expression for full subtractor. | Understand | CO 4 | AECB05.17 |
| 10 | Design half adder using AND \& OR gates. | Remember | CO 4 | AECB05.17 |
| MODULE-VSEQUENTIAL CIRCUITS FUNDAMENTALS |  |  |  |  |
| Part - A (Short Answer Questions) |  |  |  |  |
| 1. | Differentiate combinational and sequential logic circuits? | Understand | CO 5 | AECB05.19 |
| 2. | Explain basic difference between a shift register and counter? | Understand | CO 5 | AECB05.20 |
| 3. | Illustrate applications of shift registers? | Remember | CO 5 | AECB05.20 |
| 4. | Define bidirectional shift register? | Remember | CO 5 | AECB05.20 |
| 5. | Differentiate Flip-flop and latch? | Analysis | CO 5 | AECB05.19 |
| 6. | Define Counter? | Remember | CO 5 | AECB05.21 |
| 7. | Classify the basic types of counters? | Understand | CO 5 | AECB05.21 |
| 8. | Differentiate the advantages and disadvantages of ripple counters? | Understand | CO 5 | AECB05.21 |
| 9 | Describe the applications of counters? | Understand | CO 5 | AECB05.21 |
| 10 | Design D-latch using NAND? | Understand | CO 5 | AECB05.19 |
| 11 | Design and explain gated latch logic diagram? | Understand | CO 5 | AECB05.19 |
| 12 | Define race around condition? How it can be avoided? | Remember | CO 5 | AECB05.19 |
| 13 | Convert the following JK Flip Flop to using, i) SR ii) T iii) D | Understand | CO 5 | AECB05.21 |
| 14 | Convert the following SR Flip-Flop to using, <br> i) JK <br> ii) D <br> iii) T | Remember | CO 5 | AECB05.21 |
| 15 | Explain what is a synchronous latch? | Remember | CO 5 | AECB05.19 |
| 16 | Construct a latch using universal gates? | Understand | CO 5 | AECB05.19 |
| 17 | Explain what do you mean a stable state? | Remember | CO 5 | AECB05.21 |
| 18 | Define a Flip-Flop? | Remember | CO 5 | AECB05.19 |
| 19 | Define applications of Flip-Flops? | Remember | CO 5 | AECB05.19 |
| 20 | Explain what is meant by clocked flip-flop? | Understand | CO 5 | AECB05.19 |
| Part - B (Long Answer Questions) |  |  |  |  |
| 1 | Explain the design of Synchronous Sequential circuit with an example? | Understand | CO 5 | AECB05.21 |
| 2 | Write short notes on shift register? Mention its application along with the Serial Transfer in 4-bit shift Registers? | Remember | CO 5 | AECB05.20 |
| 3 | Explain about Binary Ripple Counter? What is MOD counter? | Understand | CO 5 | AECB05.21 |
| 4 | How do you convert Jk- Flip Flop to SR- Flip Flop | Remember | CO 5 | AECB05.21 |
| 5 | How do you convert T- Flip Flop to SR- Flip Flop | Understand | CO 5 | AECB05.21 |
| 6 | How do you convert D- Flip Flop to T- Flip Flop | Understand | CO 5 | AECB05.21 |
| 7 | Design a Modulo-12 up Synchronous counters using T-Flip Flops and draw the Circuit diagram for synchronous mod-12 counter? | Understand | CO 5 | AECB05.21 |
| 8 | Explain the Ripple counter design. Also the decade counters design? | Understand | CO 5 | AECB05.21 |
| 9 | Design a 3 bit ring counter? Discuss how ring counters differ from twisted ring counter? | Understand | CO 5 | AECB05.21 |
| 10 | Design a Johnson counter? | Understand | CO 5 | AECB05.21 |
| 11 | Design Johnson ounters and state its advantages and Disadvantages? | Understand | CO 5 | AECB05.21 |
| 12 | Explain with the help of a block diagram, the basic components of a Sequential Circuit? | Understand | CO 5 | AECB05.19 |


| 13 | Explain about RS and JK flip-flops with functional diagram <br> and Truth tables? | Understand | CO 5 | AECB05.19 |
| :---: | :--- | :--- | :--- | :--- |
| 14 | Define T - Flip-flop with the help of a logic diagram and <br> characteristic table? | Remember | CO 5 | AECB05.19 |
| 15 | Define Latch. Explain about SR-Latch using NAND and NOR <br> gates. | Remember | CO 5 | AECB05.19 |
| 16 | Construct the transition table for the following flip-flops <br> SRFF, DFF | Remember | CO 5 | AECB05.21 |
| 17 | Differentiate Synchronous and Asynchronous counters? | Remember | CO 5 | AECB05.21 |
| 18 | What do you mean by <br> a) latch b) gated latch. | Remember | CO 5 | AECB05.21 |
| 19 | Differentiate between gated SR- latch and edge triggered SR- <br> Flip Flop. | Remember | CO 5 | AECB05.21 |
| 20 | How do you convert Jk- Flip Flop to D- Flip Flop | Remember | CO 5 | AECB05.21 |
| 1 | Explain the JK and Master slave Flip-flop? Give its timing <br> waveform? | Understand | CO 5 | AECB05.21 |
| 2 | Define JK - Flip-flop with the help of a logic diagram and <br> characteristic table? | Remember | CO 5 | AECB05.19 |
| 3 | Design and implement 4-bit binary counter (using D flip flops) <br> which counts all possible odd numbers only? | Understand | CO 5 | AECB05.21 |
| 4 | List the characteristic equations for RS,JK,T and data Flip- <br> Flops? | Remember | CO 5 | AECB05.19 |
| 5 | Describe the steps involved in design of asynchronous <br> sequential circuit in detail with an example? | Understand | CO 5 | AECB05.21 |
| 6 | Design a MOD-5 synchronous counter using flip flops and <br> Implement it? Also draw the timing diagram? | Understand | CO 5 | AECB05.21 |
| 7 | Design a Ring counter using JK flip-flop? | Remember | CO 5 | AECB05.21 |
| 8 | Design a Twisted Ring counter using JK flip-flop? | Remember | CO 5 | AECB05.21 |
| 9 | Design MOD5 up and Down counter? | Remember | CO 5 | AECB05.21 |
| 10 | How do you convert Jk- Flip Flop to T- Flip Flop | CO 5 | AECB05.21 |  |

## Prepared by

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